PJQ5468A

CONDUCTOR

60V N-Channel Enhancement Mode MOSFET DFN5060-8L

Current

Voltage

PAN

25 A

03

Features

- $R_{DS(ON)}$, V_{GS} @10V, I_D @15A<34m Ω
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@10A<40m\Omega$

60 V

- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams •
- Marking: Q5468A

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _c =25°C	1	25		
	T _C =100°C		16	А	
Pulsed Drain Current (Note 1)	T _c =25°C	I _{DM}	100		
Power Dissipation	T _c =25°C	D	40	10/	
	T _C =100°C	PD	16	W	
Continuous Drain Current	T _A =25°C	1	5.5	А	
	T _A =70°C	I _D	4.4	А	
Power Dissipation	T _A =25°C	D	2.0	244	
Power Dissipation	T _A =70°C	PD	1.3	W	
Single Pulse Avalanche Energy (Note 6)		E _{AS}	24	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
(Note 4.5)	Junction to Case	$R_{ extsf{ heta}JC}$	3.1	°C/W	
Typical Thermal Resistance ^(Note 4,5)	Junction to Ambient	$R_{ extsf{ heta}JA}$	62.5		

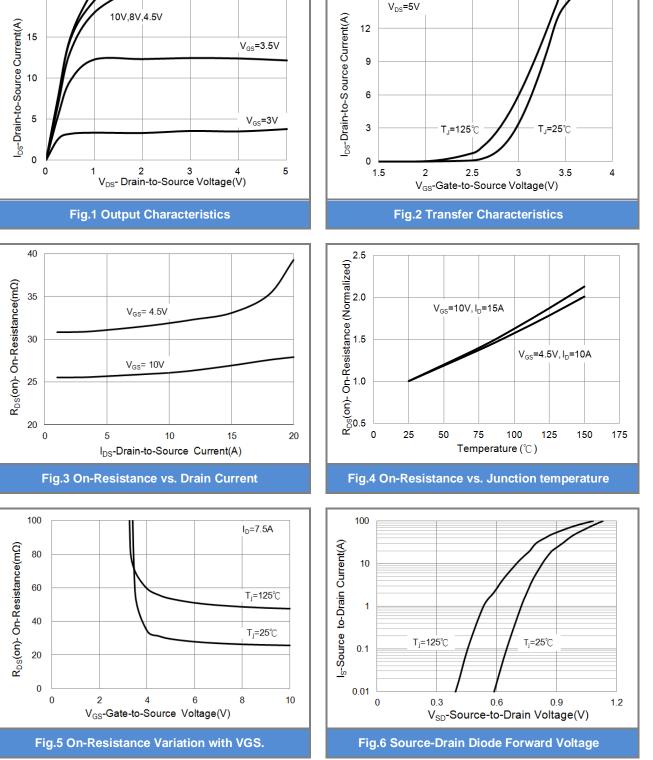


Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1.0	1.83	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =15A	-	28	34	mΩ
		V _{GS} =4.5V,I _D =10A	-	33	40	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Qg	V _{DS} =30V, I _D =20A, V _{GS} =10V ^(Note 1,2)	-	20	-	nC
Gate-Source Charge	Q _{gs}		-	3.8	-	
Gate-Drain Charge	Q _{gd}		-	3.9	-	
Input Capacitance	Ciss	$V_{DS}=25V, V_{GS}=0V,$	-	1173	-	pF
Output Capacitance	Coss		-	63	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	44	-	
Turn-On Delay Time	td _(on)		-	7.1	-	ns
Turn-On Rise Time	tr	V _{DD} =15V, I _D =1A, V _{GS} =10V, R _G =6Ω (Note 1,2)	-	25	-	
Turn-Off Delay Time	td _(off)		-	31	-	
Turn-Off Fall Time	t _f		-	20	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	25	А
Diode Forward Current	I _S					
Diode Forward Voltage	V _{SD}	I _S =1A,V _{GS} =0V	-	0.72	1.2	V

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, $I_{AS}{=}22A,\,V_{DD}{=}25V,\,V_{GS}{=}10V$
- 7. Guaranteed by design, not subject to production testing.



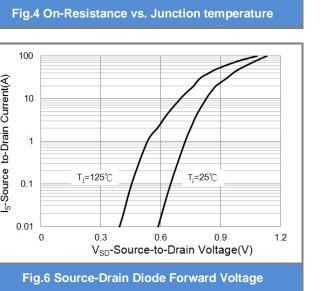
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TYPICAL CHARACTERISTIC CURVES

SEMI CONDUCTOR

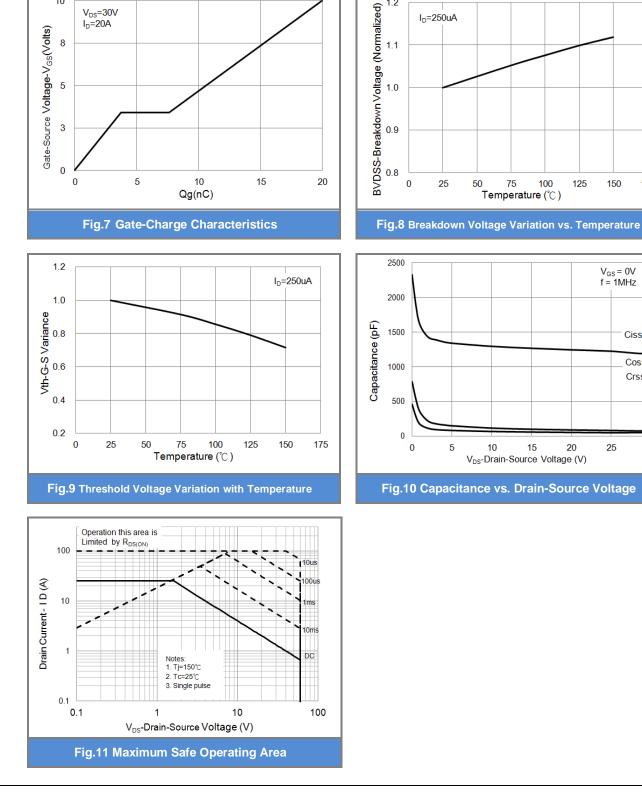
PANJIT

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1.2

1.1

 $I_D = 250 uA$

PJQ5468A

 V_{DS} =30V I_{D} =20A

TYPICAL CHARACTERISTIC CURVES



10

8



175

150

V_{GS} = 0V f = 1MHz

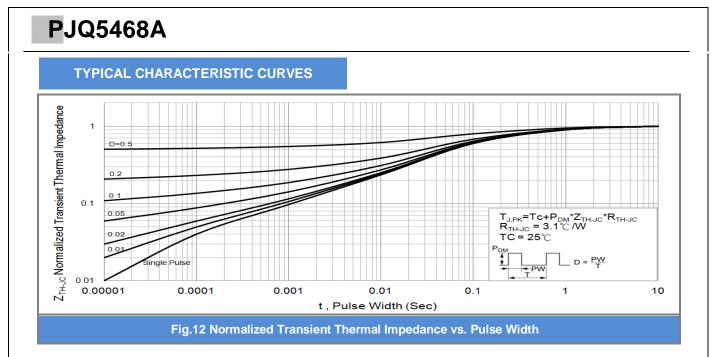
Ciss

Coss

Crss

25

30









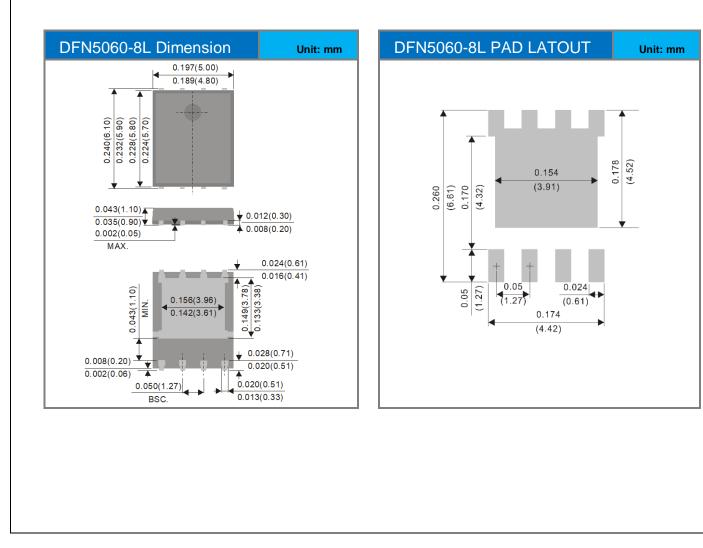


PJQ5468A

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version	
PJQ5468A_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5468A	Halogen free	

Packaging Information & Mounting Pad Layout





PJQ5468A

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